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OPTICAL SECOND HARMONIC GENERATION IN GAN WAVEGUIDE STRUCTURE

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To create modal phase matching, most common approach is to use periodic poling structure, which can be troubling to manufacture. Our research investigates attractive all *GaN* based structure with modal phase matching second harmonic generation abilities. Our goal was to grow second-harmonic generator (SHG) *N*-polar $GaN/Al_2O_3/Ga$ -polar GaN/AlGaN/AlN/Sapphire using metal-organic chemical vapor deposition (MOCVD) technique for Nd : *YAG* lasers. For our theoretical model main variable was width of *GaN* layers. The waveguide structure of 507*nm Ga*-polar and 91*nm N*-polar *GaN* sandwich, separated by 20*nm* atomic layer deposition (ALD) of an Al_2O_3 layer was grown on sapphire and 420*nm AlGaN* epilayer. Structure was tested using endfire method with femtosecond laser and peak conversion was observed around 1080*nm*. In conclusion by changing widths of *GaN* layers, this structure SHG can be used for tunable spectrum second-harmonic generation, but more research and fine tuning is required